


	<h2 style="color: red;">FQP30N06</h2>
	Hersteller-Teilenummer: FQP30N06
	Hersteller / Marke: AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung: MOSFET N-CH 60V 30A TO-220
	Datenblätter: <ul style="list-style-type: none">  1.FQP30N06.pdf  2.FQP30N06.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 119973 pcs Stock Available.
	Liefern von: Hong Kong
	Versandweg: DHL/Fedex/TNT/UPS/EMS
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQP30N06
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 30A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	119973 pcs Stock
Hersteller Standard Vorlaufzeit	4 Weeks
detaillierte Beschreibung	N-Channel 60V 30A (Tc) 79W (Tc) Through Hole TO-
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220AB
Verlustleistung (max)	79W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	30A (Tc)
Rds On (Max) @ Id, Vgs	40 mOhm @ 15A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	25nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	945pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FQP30N06-ND



















































FQP30N06 ist neu im Original. Suche FQP30N06 Datenblätter, PDF, Inventar bei Y-IC.com Online. Bestellen Sie FQP30N06 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQP30N06: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQP2P40 AMI Semiconductor / ON Semiconductor MOSFET P-CH 400V 2A TO-220</p>	 <p>FQP30N10 Original TO-220</p>	 <p>FQP2P40-F080 AMI Semiconductor / ON Semiconductor MOSFET P-CH 400V 2A TO-220</p>	 <p>FQP2P25 Fairchild/ON Semiconductor MOSFET P-CH 250V 2.3A TO-220</p>
 <p>FQP30N06L Fairchild/ON Semiconductor MOSFET N-CH 60V 32A TO-220</p>	 <p>FQP2P40 Fairchild/ON Semiconductor MOSFET P-CH 400V 2A TO-220</p>	 <p>FQP30N06 Fairchild/ON Semiconductor MOSFET N-CH 60V 30A TO-220</p>	 <p>FQP2P40_F080 Fairchild/ON Semiconductor MOSFET P-CH 400V 2A TO-220</p>

heiße Teile

Mehr

 FQP19N20L	 FQP1N60C	 FQP20N06	 D FQP20N06	 FQP20N06L
 FQP20N06L	 FQP20N06TSTU	 D FQP20N06TSTU	 FQP20N60	 FQP22N30
 FQP22N30	 FQP22P10	 FQP22P10	 FQP24N08	 FQP24N08
 D FQP24N40	 FQP27N25	 FQP27N25	 FQP27N60	 FQP27P06
 FQP27P06	 FQP2N60B	 FQP2N60C	 FQP2N60C	 FQP2N65C
 FQP30N06	 FQP30N06L	 D FQP30N06L	 FQP32N12V2	 FQP32N12V2
 FQP32N20	 D FQP32N20C	 FQP32N20C	 FQP33N10	 FQP33N10
 FQP33N10L	 FQP33N10L	 FQP34N20	 FQP34N20	 FQP34N20L
 FQP34N20L	 FQP3N50C	 FQP3N60C	 D FQP3N60C	 FQP3N80C
 FQP3N80C	 FQP44N08	 FQP44N08	 FQP44N10	 FQP44N10

Contact us: Info@Y-IC.com

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